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Sample-to-sample torque fluctuations in a system of coaxial randomly charged surfaces

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Abstract. Polarizable randomly charged dielectric objects have been recently shown to exhibit long-range lateral and normal interaction forces even when they are effectively net-neutral. These forces stem from an interplay between the quenched statistics of random charges and the induced dielectric image charges. This type of interaction has recently been evoked to interpret measurements of Casimir forces *in vacuo*, where a precise analysis of such disorder-induced effects appears to be necessary. Here we consider the torque acting on a randomly charged dielectric surface (or a sphere) mounted on a central axle next to another randomly charged surface and show that although the resultant mean torque is zero, its sample-to-sample fluctuation exhibits a long-range behavior with the separation distance between the juxtaposed surfaces and that, in particular, its root-mean-square value scales with the total area of the surfaces. Therefore, the disorder-induced torque between two randomly charged surfaces is expected to be much more pronounced than the disorder-induced lateral force and may provide an effective way to determine possible disorder effects in experiments, in a manner that is independent of the usual normal force measurement.

1 Introduction

The surfaces of dielectrics, crystalline solids and metals often exhibit random monopolar charge distributions [1–8]. Random charges may result from adsorption of contaminants and/or the presence of impurities that can generate surface charges which depend strongly on the method of preparation of the samples. Surface charge disorder may also originate from the variation of the local crystallographic axes of the exposed surface of a clean polycrystalline sample which induces a variation of the local surface potential [2–9]. The heterogeneous structure of the charge disorder on dielectric surfaces and thus its statistical properties can be determined directly from Kelvin force microscopy measurements [1]. Randomly charged surfaces are equally abundant in colloidal and soft matter systems [10–12], examples arise in surfactant-coated

surfaces [13–16], unstructured proteins and random polyelectrolytes and polyampholytes [17, 18].

A number of authors [2–7] have pointed out that disorder effects may significantly influence the measurement of the Casimir-van der Waals (vdW) forces between solid surfaces in vacuum. These forces act between all objects and are relatively short-ranged in nature. Recent ultrahigh sensitivity experiments of the Casimir force have however revealed a residual long-range interaction force which dominates at sufficiently large separations, and it has been suggested that it is due to surface disorder effects [2–7].

Recently it has been proposed that quenched random charge disorder on surfaces as well as in the bulk of dielectric slabs can lead to long-range interactions even when the surfaces are net-neutral [19, 20]. These long-range interactions stem from a subtle interplay between the quenched statistics of surface or bulk charges and the image charge effects generated by the dielectric discontinuities present at the bounding surfaces.

It was subsequently demonstrated [21] that two randomly charged surfaces can interact with both random *normal* forces, whose mean value turns out to be *finite*

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and long-ranged as noted above, and random *lateral* forces, which—for two juxtaposed planar surfaces carrying statistically homogeneous random charges—turn out to be *zero* on the average. Both quantities however show sample-to-sample fluctuations whose root-mean-square value also exhibits a long-range behavior with the separation distance between the surfaces.

In this study, we pursue our analysis of disorder effects on long-range interactions and investigate the torque acting on a randomly charged planar or (spherical) dielectric object mounted on a central axle next to a randomly charged dielectric substrate. We show that although the resultant mean torque in this system is zero, its sample-to-sample fluctuation exhibits a long-range behavior with the separation distance. Even more importantly, the root-mean-square value of the torque fluctuations scales with the total area of the surfaces and thus represents an extensive quantity. Therefore, the disorder-induced torque between two randomly charged surfaces is expected to be much more pronounced than the disorder-induced lateral force and may present a more effective method to quantify charge disorder effects in experiments. Our results on disorder-induced torque may also be related to the so-called lock and key phenomena, which underpin highly specific interactions between complex biological molecules such as proteins, where long-range electrostatic interactions can induce pre-alignment which enables complex molecules to interact in a biologically useful manner [22–24].

2 Two plane-parallel dielectric slabs

Consider two plane-parallel dielectric half-spaces with the bounding surfaces separated in the z direction by a distance l . The surface at $z = 0$ belongs to a dielectric half-space with the dielectric constant ε_2 and the surface at $z = l$ belongs to a dielectric half-space with the dielectric constant ε_1 (see fig. 1). We call these surfaces S_2 and S_1 , respectively. We denote by ε_m the dielectric constant of the intervening material. Let each surface (labelled by $\alpha, \beta = 1, 2$) have a random surface charge density $\rho_\alpha(\mathbf{x}) = \rho_\alpha(\mathbf{r}, z)$ with zero mean (*i.e.*, the surfaces are *net-neutral*) and the correlation function in the plane of the slabs ($\mathbf{r}, \mathbf{r}' \in S_1, S_2$)

$$\langle \rho_\alpha(\mathbf{r}, z) \rho_\beta(\mathbf{r}', z') \rangle = \delta_{\alpha\beta} g_{\alpha s} \delta(z - l_\alpha) \delta(z' - l_\beta) C_\alpha(\mathbf{r} - \mathbf{r}'), \quad (1)$$

where we define $l_2 = 0$ and $l_1 = l$. In addition, we assume that the charge distribution on surface S_1 is restricted to a finite area A . The surface S_1 is assumed to be mounted on an axle that allows for rotation around its central symmetry axis. In the case where the random charge is made up of point charges of signs $\pm e$ of surface density $n_{\alpha s}$, we may write the variance of the charge disorder as $g_{\alpha s} = e^2 n_{\alpha s}$. The correlation function $C(\mathbf{r} - \mathbf{r}')$ has dimensions of inverse length squared, meaning that its two-dimensional Fourier transform is dimensionless. Typically the values of n_s for reasonably pure samples are smaller than the

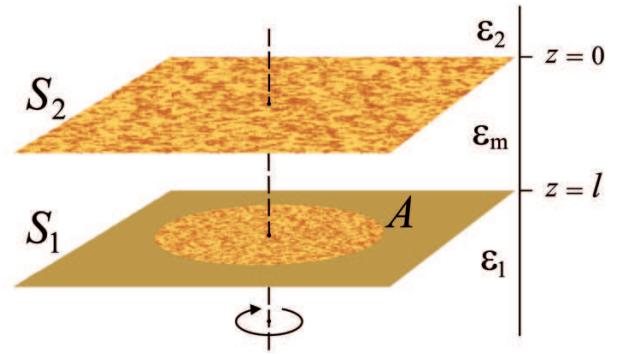


Fig. 1. (Color online) Schematic representation of two dielectric half-spaces at a separation distance of l carrying quenched random charges (shown by small dark and light brown patches) on their bounding surfaces. The charges on the lower surface are assumed to be distributed in a circular region of area A , which is then taken to infinity. The lower surface is allowed to rotate around the central z axis as shown in the figure.

bulk disorder variance which is usually in the range between 10^{-11} and 10^{-6} nm^{-3} (corresponding to impurity charge densities of 10^{10} to 10^{15} e/cm^3 [19, 20, 25, 26]).

The electrostatic energy of the system is given by

$$E = \frac{1}{2} \int d\mathbf{x} \phi(\mathbf{x}) \rho(\mathbf{x}), \quad (2)$$

where $\rho(\mathbf{x})$ is the total charge density and

$$\phi(\mathbf{x}) = \int d\mathbf{y} G(\mathbf{x}, \mathbf{y}) \rho(\mathbf{y}) \quad (3)$$

is the electrostatic potential, while $G(\mathbf{x}, \mathbf{y})$ is the Green's function obeying

$$\varepsilon_0 \nabla \cdot [\varepsilon(\mathbf{x}) \nabla G(\mathbf{x}, \mathbf{y})] = -\delta(\mathbf{x} - \mathbf{y}), \quad (4)$$

with $\varepsilon(\mathbf{x})$ being the local dielectric function. Upon changing the charge distribution the corresponding change in the energy of the system is thus given by

$$\delta E = \int d\mathbf{x} d\mathbf{y} \delta \rho(\mathbf{x}) G(\mathbf{x}, \mathbf{y}) \rho(\mathbf{y}). \quad (5)$$

If the charge distribution on the surface S_1 , $\rho_1(\mathbf{x})$, is made up of point charges, we have

$$\rho_1(\mathbf{x}) = \sum_{n \in S_1} q_n \delta(\mathbf{x} - \mathbf{x}_n), \quad (6)$$

where q_n is the charge at the site \mathbf{x}_n . Now on rotating the surface S_1 by an angle θ around its symmetry axis, that is to say in the direction perpendicular to the normal between the bounding surfaces of the two dielectric media, we find that the new charge distribution is given by

$$\rho'_1(\mathbf{x}) = \sum_{n \in S_1} q_n \delta(\mathbf{r} - \hat{R}_\theta \mathbf{r}_n) \delta(z - z_n), \quad (7)$$

where \hat{R}_θ is the two-dimensional rotation matrix. For an infinitesimal rotation angle $\delta\theta$, one has $\hat{R}_{\delta\theta} = 1 - i(\delta\theta) \hat{\sigma}_2$,

where $\hat{\sigma}_2 = \begin{pmatrix} 0 & -i \\ i & 0 \end{pmatrix}$ is the Pauli matrix. This means that we can write (assuming the summation over the in-plane Cartesian components $i, j = 1, 2$ and using the fact that the diagonal elements of $\hat{\sigma}_2$ are zero)

$$\begin{aligned} \delta\rho(\mathbf{x}) &= \delta\rho_1(\mathbf{x}) = i(\delta\theta) (\hat{\sigma}_2)_{ij} \sum_{n \in S_1} q_n(\mathbf{r}_n)_j \\ &\times \frac{\partial}{\partial r_i} \delta(\mathbf{r} - \mathbf{r}_n) \delta(z - z_n) = i(\delta\theta) (\hat{\sigma}_2)_{ij} r_j \frac{\partial}{\partial r_i} \rho_1(\mathbf{x}). \end{aligned} \quad (8)$$

As the surface S_1 is rotated the self-interaction between the charges on each surface is unchanged, thus the energy change is only given by the interaction of the charges and image charges in S_1 with those in S_2 . We may thus write

$$\begin{aligned} \delta E &= i(\delta\theta) (\hat{\sigma}_2)_{ij} \int d\mathbf{r}' d\mathbf{r} dz dz' \left[r'_j \frac{\partial}{\partial r'_i} \rho_1(\mathbf{r}', z') \right] \\ &\times G(\mathbf{r} - \mathbf{r}'; z, z') \rho_2(\mathbf{r}, z), \end{aligned} \quad (9)$$

where \mathbf{r}' and \mathbf{r} are again the two-dimensional coordinates in the planes of S_1 and S_2 , respectively, and z and z' are the respective coordinates normal to the planes. We thus note that the integration over the coordinate \mathbf{r}' is over a finite area A , while that over \mathbf{r} is unrestricted. The torque τ acting on the surface S_1 is thus given by $\delta E = -(\delta\theta) \tau$. As the charge distribution on the surfaces S_1 and S_2 are uncorrelated, we find that $\langle \delta E \rangle = -(\delta\theta) \langle \tau \rangle = 0$, where $\langle \dots \rangle$ denotes the ensemble average over the random charge distributions. Thus the mean torque is zero. The variance of the torque is obtained using $\langle (\delta E)^2 \rangle = (\delta\theta)^2 \langle \tau^2 \rangle$ as

$$\begin{aligned} \langle \tau^2 \rangle &= -(\hat{\sigma}_2)_{ij} (\hat{\sigma}_2)_{mp} \left\langle \int d\mathbf{r}' d\mathbf{r} dz dz' ds' ds d\zeta d\zeta' \right. \\ &\times \left[r'_j \frac{\partial}{\partial r'_i} \rho_1(\mathbf{r}', z') \right] G(\mathbf{r} - \mathbf{r}'; z, z') \rho_2(\mathbf{r}, z) \\ &\times \left[s'_p \frac{\partial}{\partial s'_m} \rho_1(\mathbf{s}', \zeta') \right] G(\mathbf{s} - \mathbf{s}'; \zeta, \zeta') \rho_2(\mathbf{s}, \zeta) \left. \right\rangle, \end{aligned} \quad (10)$$

where as before $\mathbf{r}', \mathbf{s}' \in S_1$, $\mathbf{r}, \mathbf{s} \in S_2$ and the summation is again over the in-plane Cartesian components $i, j, m, p = 1, 2$. Again as the charge distributions on the two surfaces are assumed to be uncorrelated, the only non-zero correlations in the above are given by

$$\langle \rho_2(\mathbf{r}, z) \rho_2(\mathbf{s}, \zeta) \rangle = g_{2s} \delta(z) \delta(\zeta) C_2(\mathbf{r} - \mathbf{s}), \quad (11)$$

$$\langle \rho_1(\mathbf{r}', z') \rho_1(\mathbf{s}', \zeta') \rangle = g_{1s} \delta(z' - l) \delta(\zeta' - l) C_1(\mathbf{r}' - \mathbf{s}'). \quad (12)$$

This then yields

$$\begin{aligned} \langle \tau^2 \rangle &= -(\hat{\sigma}_2)_{ij} (\hat{\sigma}_2)_{mp} g_{1s} g_{2s} \\ &\times \int d\mathbf{r}' d\mathbf{r} ds' ds G(\mathbf{r} - \mathbf{r}'; 0, l) G(\mathbf{s} - \mathbf{s}'; 0, l) C_2(\mathbf{r} - \mathbf{s}) \\ &\times \left[r'_j s'_p \frac{\partial}{\partial r'_i} \frac{\partial}{\partial s'_m} C_1(\mathbf{r}' - \mathbf{s}') \right]. \end{aligned} \quad (13)$$

We now write the above result in terms of the two-dimensional in-plane Fourier transforms \tilde{G} and \tilde{C}_2 of the functions G and C_2 and carry out the integrations over the coordinates \mathbf{r} and \mathbf{s} of the infinite plane S_2 to obtain

$$\begin{aligned} \langle \tau^2 \rangle &= -(\hat{\sigma}_2)_{ij} (\hat{\sigma}_2)_{mp} g_{1s} g_{2s} \int \frac{d\mathbf{k}}{(2\pi)^2} \tilde{G}(\mathbf{k}; 0, l) \\ &\times \tilde{G}(-\mathbf{k}; 0, l) \tilde{C}_2(-\mathbf{k}) J_{jpim}(\mathbf{k}). \end{aligned} \quad (14)$$

Now we have to evaluate the integral over coordinates of S_1 which has the form

$$\begin{aligned} J_{jpim}(\mathbf{k}) &= \int_{S_1 \times S_1} d\mathbf{r}' ds' \\ &\times \left[r'_j s'_p \frac{\partial}{\partial r'_i} \frac{\partial}{\partial s'_m} C_1(\mathbf{r}' - \mathbf{s}') \right] e^{-i\mathbf{k} \cdot (\mathbf{r}' - \mathbf{s}')}. \end{aligned} \quad (15)$$

In order to proceed we must assume that the correlation length of the charge disorder is much smaller than the linear dimensions of the area A on S_1 which is covered by random charges. We introduce the relative coordinate $\mathbf{u}' = \mathbf{r}' - \mathbf{s}'$ to obtain

$$\begin{aligned} J_{jpim}(\mathbf{k}) &= - \int_{S_1 \times S'_1} d\mathbf{r}' d\mathbf{u}' \\ &\times \left[r'_j (r'_p - u'_p) \frac{\partial}{\partial u'_i} \frac{\partial}{\partial u'_m} C_1(\mathbf{u}') \right] e^{-i\mathbf{k} \cdot \mathbf{u}'}, \end{aligned} \quad (16)$$

where S'_1 is the shifted integration region over \mathbf{u}' . Now with the assumption that the correlation length of the charge disorder is much smaller than the linear dimensions of the area A on S_1 we see that the first term above dominates for a large system. Furthermore, we can take the integration over \mathbf{u}' to be over \mathbb{R}^2 to obtain

$$J_{jpim} = k_i k_m \tilde{C}_1(\mathbf{k}) K_{jp}, \quad (17)$$

where

$$K_{jp} = \int_{S_1} d\mathbf{r} r_j r_p. \quad (18)$$

This then gives the general result

$$\begin{aligned} \langle \tau^2 \rangle &= -g_{1s} g_{2s} \int \frac{d\mathbf{k}}{(2\pi)^2} \tilde{G}(\mathbf{k}; 0, l) \tilde{G}(-\mathbf{k}; 0, l) \\ &\times \tilde{C}_2(\mathbf{k}) \tilde{C}_1(\mathbf{k}) [(\hat{\sigma}_2)_{ij} (\hat{\sigma}_2)_{mp} k_i k_m K_{jp}]. \end{aligned} \quad (19)$$

This formula can then be applied to a general finite two-dimensional charged area A of arbitrary shape assuming that it is sufficiently large. An alternative, more geometric form of this result is

$$\begin{aligned} \langle \tau^2 \rangle &= g_{1s} g_{2s} \int \frac{d\mathbf{k}}{(2\pi)^2} \tilde{G}(\mathbf{k}; 0, l) \tilde{G}(-\mathbf{k}; 0, l) \\ &\times \tilde{C}_2(\mathbf{k}) \tilde{C}_1(\mathbf{k}) \int_{S_1} d\mathbf{r} |\mathbf{k} \times \mathbf{r}|^2, \end{aligned} \quad (20)$$

where the integration over S_1 is about the axis of rotation. Specializing to the case where the area A on the surface

S_1 is a disc and the axis of rotation is at its center, we find that

$$K_{jp} = \delta_{jp} \frac{\pi R^4}{4} = \delta_{jp} \frac{A^2}{4\pi}, \quad (21)$$

where R is the disc radius and $A = \pi R^2$ is its area. Now using the fact that $(\hat{\sigma}_2)_{ij}(\hat{\sigma}_2)_{mj} = -\delta_{im}$ and that $\tilde{G}(\mathbf{k})$ and $\tilde{C}_\alpha(\mathbf{k})$ are functions of $|\mathbf{k}| = k$ only, we may write

$$\langle \tau^2 \rangle = \frac{A^2 g_{1s} g_{2s}}{8\pi^2} \int dk k^3 [\tilde{G}(k; 0, l)]^2 \tilde{C}_2(k) \tilde{C}_1(k), \quad (22)$$

which is the final expression of the torque fluctuations in the plane-parallel geometry. This result may then be compared with the lateral force fluctuations which were derived in the form [21]

$$\langle F_i^{(L)} F_j^{(L)} \rangle = \frac{A \delta_{ij} g_{1s} g_{2s}}{2\pi} \int k dk k_i k_j [\tilde{G}(k; 0, l)]^2 \tilde{C}_1(k) \tilde{C}_2(k), \quad (23)$$

leading to an intuitively clear physical relation between the lateral force fluctuations and the torque fluctuations of the form

$$\langle \tau^2 \rangle = \frac{1}{A} \langle F_i^{(L)} F_j^{(L)} \rangle I_{ij}, \quad (24)$$

where we have used the summation convention and the moment of inertia tensor definition as

$$I_{ij} = \int_{S_1} d\mathbf{r} (\delta_{ij} r^2 - r_i r_j). \quad (25)$$

The torque fluctuations are thus connected with the lateral force fluctuations through a geometric factor encoded by moment of inertia tensor. This result is completely general and valid for the assumed plane-parallel arrangement of the two disorder-carrying dielectric surfaces.

2.1 General scaling of torque fluctuations

We can now proceed to a general analysis of the torque fluctuations in terms of the area of the interacting surfaces A as well as the normal separation between them l . As the lateral force fluctuations have the following scaling with respect to A and l [21]

$$\langle F_i^{(L)} F_j^{(L)} \rangle \sim \frac{A}{l^2}, \quad (26)$$

it follows that typical torque fluctuations (or its room-mean-square τ_{rms}) scale as

$$\tau_{\text{rms}} \sim \frac{A}{l}, \quad (27)$$

which is thus *extensive* in terms of the area A . In other words, the magnitude of the variance of the random torque exhibits a non-extensive scaling with area. This is as one might expect, because torque is determined by the geometry of the area A even in the limit of large area (which is not the case for the random lateral force [21]). However the geometry dependence of the torque fluctuations

and the scaling with the area A are obtained simply from the moment of inertia tensor. For instance, if instead of a disc-shaped area, one considers a square of area A on the surface S_1 which can rotate about its center, then one finds that $K_{jp} = \delta_{jp} A^2/12$ and consequently

$$\langle \tau^2 \rangle = \frac{A^2 g_{1s} g_{2s}}{24\pi} \int dk k^3 [\tilde{G}(k; 0, l)]^2 \tilde{C}_2(k) \tilde{C}_1(k). \quad (28)$$

The torque fluctuations for a square are thus slightly larger than that for a disc of the same area as one would intuitively expect.

2.2 Torque fluctuations in a homogeneous system

In the case where there are no dielectric jumps at the boundaries ($\varepsilon_1 = \varepsilon_2 = \varepsilon_m$) and the charge disorder is uncorrelated $C_\alpha(\mathbf{r} - \mathbf{r}') = \delta(\mathbf{r} - \mathbf{r}')$, the expression (22) reduces to

$$\langle \tau^2 \rangle = \frac{g_{1s} g_{2s} A^2}{128\pi^2 \varepsilon_0^2 \varepsilon_m^2 l^2}. \quad (29)$$

This result can be obtained in a direct, more geometric manner, by starting from the variation in the bare Coulomb energy upon rotating the surface S_1 by a small angle around its central axis,

$$\delta E = \frac{1}{4\pi \varepsilon_0 \varepsilon_m} \int d\mathbf{x} d\mathbf{y} \frac{\delta \rho_1(\mathbf{x}) \rho_2(\mathbf{y})}{|\mathbf{x} - \mathbf{y}|}, \quad (30)$$

and showing after some manipulations that

$$\langle \tau^2 \rangle = \frac{g_{1s} g_{2s}}{(4\pi \varepsilon_0 \varepsilon_m)^2} \int d\mathbf{s} d\mathbf{r} \frac{(s_x r_y - s_y r_x)^2}{[(\mathbf{r} - \mathbf{s})^2 + l^2]^3} = \frac{g_{1s} g_{2s} A^2}{128\pi^2 \varepsilon_0^2 \varepsilon_m^2 l^2}. \quad (31)$$

3 Torque fluctuations in the sphere-plane geometry

Let us now consider a sphere (S_2) of radius R apposed to a planar substrate (S_1) at a minimum separation of l (see fig. 2), both carrying quenched random charges of density (variance) g_{1s} and g_{2s} over their surfaces only. The substrate is assumed to be fixed and the sphere is assumed to be mounted on an axle that allows for rotation around the z axis.

We shall first focus on the case where there are no dielectric inhomogeneities at the boundaries ($\varepsilon_1 = \varepsilon_2 = \varepsilon_m$) and that the charge disorder is *uncorrelated*. The more general case of inhomogeneous dielectrics will be considered later (see below). In the absence of image charges, the sample-to-sample torque fluctuations in this system can be evaluated exactly as follows.

The variation in the charge distribution of the sphere due a small rotation $\delta\varphi$ around its central z axis can be written as $\delta\rho_2(\mathbf{x}) = -\delta\varphi \frac{\partial}{\partial\varphi} \rho_2(\mathbf{x})$, where $\mathbf{x} = (x, \theta, \varphi)$ and

$$\rho_2(\mathbf{x}) = \sum_{n \in S_2} q_n \left(\frac{1}{x^2 \sin\theta} \right) \delta(x - x_n) \delta(\theta - \theta_n) \delta(\varphi - \varphi_n) \quad (32)$$

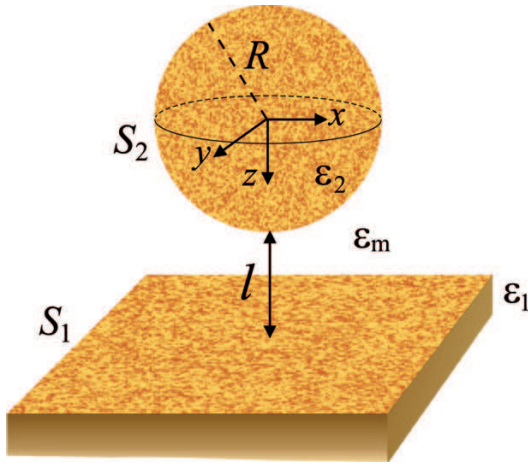


Fig. 2. (Color online) Schematic picture of a sphere (S_2) apposed to a planar substrate (S_1) at a minimum separation of l . Both objects carry random charges on their bounding surfaces (shown by small dark and light brown patches). The sphere is allowed to rotate around the central z axis.

is the sphere charge distribution made up of point charges located at positions \mathbf{x}_n . The variance of the energy of the system thus follows as

$$\langle (\delta E)^2 \rangle = \int d\mathbf{x} d\mathbf{x}' d\mathbf{y} d\mathbf{y}' \frac{\langle \rho_1(\mathbf{x}) \rho_1(\mathbf{x}') \rangle \langle \delta \rho_2(\mathbf{y}) \delta \rho_2(\mathbf{y}') \rangle}{|\mathbf{x} - \mathbf{y}| |\mathbf{x}' - \mathbf{y}'|}, \quad (33)$$

where for uncorrelated charge disorder assumed here

$$\langle \rho_1(\mathbf{x}) \rho_1(\mathbf{x}') \rangle = g_{1s} \delta(\mathbf{r} - \mathbf{r}') \delta(z - l - R) \delta(z' - l - R), \quad (34)$$

$$\begin{aligned} \langle \delta \rho_2(\mathbf{y}) \delta \rho_2(\mathbf{y}') \rangle &= (\delta \varphi)^2 \left(\frac{g_{2s}}{R^2 \sin \theta} \right) \delta(y - R) \delta(y' - R) \\ &\times \delta(\theta - \theta') \frac{\partial^2}{\partial \varphi \partial \varphi'} \delta(\varphi - \varphi'). \end{aligned} \quad (35)$$

Here we have introduced $\mathbf{x} = (\mathbf{r}, z) \in S_1$ and $\mathbf{y} = (y, \theta, \varphi) \in S_2$. Then using $\langle (\delta E)^2 \rangle = (\delta \varphi)^2 \langle \tau^2 \rangle$, we find an expression resembling eq. (31), *i.e.*

$$\begin{aligned} \langle \tau^2 \rangle &= \frac{g_{1s} g_{2s}}{(4\pi \epsilon_0 \epsilon_m)^2} \int d\mathbf{r} R^2 \sin \theta d\theta d\varphi \\ &\times \frac{(s_x r_y - s_y r_x)^2}{[(\mathbf{r} - \mathbf{s})^2 + (l + R(1 - \cos \theta))^2]^3}, \end{aligned} \quad (36)$$

where $\mathbf{s} = (R \sin \theta \cos \varphi, R \sin \theta \sin \varphi)$, or explicitly, via a parameterization of \mathbf{r} as $\mathbf{r} = (r \cos \alpha, r \sin \alpha)$, we find

$$\begin{aligned} \langle \tau^2 \rangle &= \frac{2\pi g_{1s} g_{2s}}{(4\pi \epsilon_0 \epsilon_m)^2} \int_0^\infty dr \int_0^\pi d\theta \int_0^{2\pi} d\varphi \\ &\times \frac{R^4 r^3 \sin^3 \theta \sin^2 \varphi}{[R^2 + r^2 + (l + R)^2 - 2rR \sin \theta \cos \varphi - 2R(l + R) \cos \theta]^3}. \end{aligned} \quad (37)$$

This equation can be written as

$$\langle \tau^2 \rangle = \frac{2\pi R^2 g_{1s} g_{2s}}{(4\pi \epsilon_0 \epsilon_m)^2} f\left(\frac{l}{R}\right), \quad (38)$$

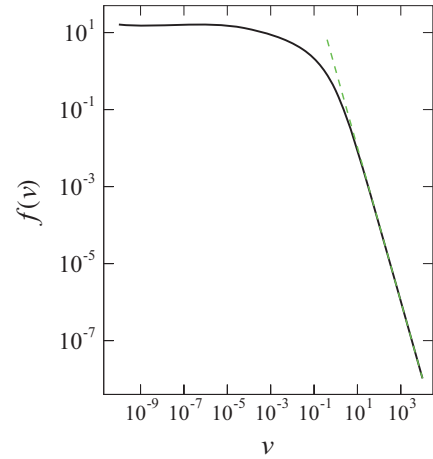


Fig. 3. (Color online) The log-log plot of the dimensionless function $f(v)$ as a function of the dimensionless sphere-substrate separation $v = l/R$ (solid line). The dashed (green) line shows the limiting behavior $f(v) \sim v^{-2}$ for large v .

where the dimensionless function $f(v)$ reads

$$\begin{aligned} f(v) &\equiv \int_0^\infty du \int_0^\pi d\theta \int_0^{2\pi} d\varphi \\ &\times \frac{u^3 \sin^3 \theta \sin^2 \varphi}{[1 + u^2 + (v + 1)^2 - 2u \sin \theta \cos \varphi - 2(v + 1) \cos \theta]^3}. \end{aligned} \quad (39)$$

Note that the same expression can be obtained if one assumes that the sphere S_2 is fixed and the substrate S_1 is allowed to freely rotate around the z axis passing through the center of the sphere.

In fig. 3, we plot the dimensionless function $f(v)$ as a function of $v = l/R$. For large separation or small sphere radius $v = l/R \gg 1$, the torque variance tends to zero and we find that $f(v) \simeq (1.0470\dots)/v^2$; hence

$$\langle \tau^2 \rangle \sim \frac{g_{1s} g_{2s} R^4}{(4\pi \epsilon_0 \epsilon_m)^2 l^2}, \quad (40)$$

whereas for small separation or large sphere radius $v = l/R \ll 1$, we find $f(v) \sim \text{const} \simeq 2\pi(16.1705\dots)$; hence

$$\langle \tau^2 \rangle \sim \frac{g_{1s} g_{2s} R^2}{(4\pi \epsilon_0 \epsilon_m)^2}. \quad (41)$$

The dielectrically inhomogeneous case where the dielectric constants of the sphere and the substrate are in general different from ϵ_m and from each other is not tractable analytically. It is nevertheless possible to provide an estimate for the torque fluctuations variance in analogy with the results presented in ref. [21] for the lateral force fluctuations in the dielectric sphere-substrate system. There it was shown, using the proximity force arguments, that the dielectric effects lead only to a correction of the prefactor of the result obtained for a homogeneous

sphere-substrate system, where the dielectric-dependent prefactor is exactly the same as obtained for two semi-infinite planar slabs [21].

This result then suggests the following heuristic estimate for the torque variance in the dielectrically inhomogeneous sphere-substrate system:

$$\langle \tau^2 \rangle = \frac{2R^2 g_{1s} g_{2s}}{\pi \varepsilon_0^2} \left[\frac{\varepsilon_m^2 |\ln(1 - \Delta_1 \Delta_2)|}{(\varepsilon_m + \varepsilon_1)^2 (\varepsilon_m + \varepsilon_2)^2 \Delta_1 \Delta_2} \right] f\left(\frac{l}{R}\right), \quad (42)$$

where $\Delta_\alpha = \frac{\varepsilon_\alpha - \varepsilon_m}{\varepsilon_\alpha + \varepsilon_m}$ for $\alpha = 1, 2$. The above result obviously reduces to the one in eq. (37) when $\varepsilon_1 = \varepsilon_2 = \varepsilon_m$.

4 Discussion and conclusions

Generalizing our previous results on the force fluctuations between charge-disordered interfaces, we have now calculated fluctuations in the torque between two coaxial randomly charged surfaces. Surprisingly, the disorder-induced torque fluctuations scale differently with the surface area of the interfaces bearing charge disorder, with the root-mean-square torque being *extensive* in the surface area A . In our opinion this opens up a feasible way to measure charge disorder-induced interactions between randomly charged media in a way which is independent of normal force measurements and with a higher signal than lateral force measurements.

The measurements we have in mind would of course have to be sample-to-sample torque fluctuations. While they decay with the separation between the bounding surfaces carrying the disordered charges in a similar way as the forces, the magnitude of torque fluctuations is \sqrt{A} times larger than the corresponding lateral or normal force fluctuations which are always comparable in magnitude. Results obtained for the sphere-plane geometry in fact indicate that the disorder effect on the torque fluctuations should be highest in this case, asymptotically leveling off at a finite value for small separations.

That vdW interactions between anisotropic media lead in general to torques induced by electromagnetic field fluctuations was first realized by Weiss and Parsegian [27,28]. The effect persists not only in the non-retarded but also in the retarded limit [29] and should be experimentally detectable with modern instrumentation [30] such as the torsion-balance-based setups [31]. It is worth stressing that in the case of vdW torques the fluctuations are in the field mediating the interactions, while the boundaries do not fluctuate and are not disordered. In the case analyzed here however, the effect is very different: the field does not fluctuate but its sources indeed are quenched in a statistically disordered state. The other important difference is that vdW torques arise due to the non-isotropic dielectric response of the interacting bodies, while the disorder-generated torque fluctuations are present even between bodies with a completely isotropic—but disordered—charge distribution, being in this sense obviously more universal.

In order to detect sample-to-sample variation in the torque or the force itself, one would have to perform many experiments measuring the value of the torque as one object is gradually rotated above the other. If the measurement of the torque at any given angle can be done to an accuracy greater than the value of the torque fluctuations estimated here, then valuable information about the effect of charge disorder-induced interactions could be extracted.

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